

1N4001-G Thru. 1N4007-G

Voltage: 50 to 1000 V

Current: 1.0 A

RoHS Device

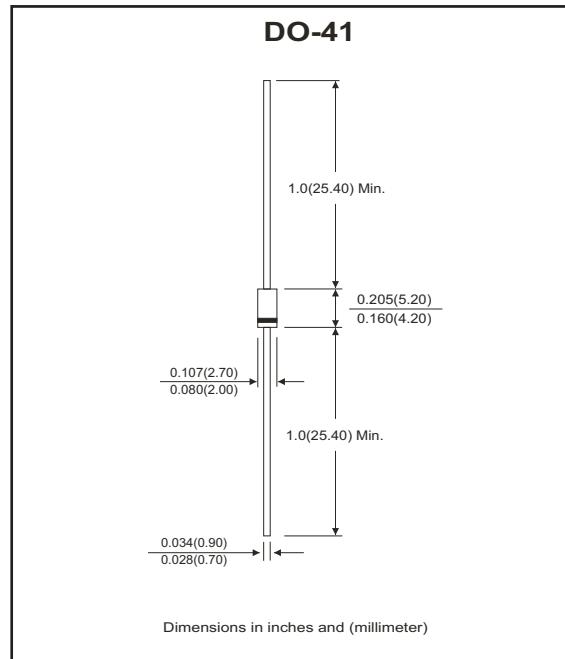


Features

- Low cost construction.
- Fast forward voltage drop.
- Low reverse leakage.
- High forward surge current capability.
- High soldering temperature guarantee: 260 °C/10 seconds, 0.375"(9.5mm) lead length at 5lbs(2.3kg) tension.

Mechanical data

- Case: transfer molded plastic, DO-41
- Epoxy: UL 94V-0 rate flame retardant
- Polarity: Indicated by cathode band
- Lead: Plated axial lead, solderable per MIL-STD-202E, method 208C
- Mounting position: Any
- Weight: 0.012ounce, 0.33 grams



Electrical Characteristics (at TA=25°C unless otherwise noted)

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load derate current by 20%.

Parameter	Symbol	1N4001 -G	1N4002 -G	1N4003 -G	1N4004 -G	1N4005 -G	1N4006 -G	1N4007 -G	Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current 0.375"(9.5mm) Lead Length @T _A =55 °C	I _(AV)					1.0			A
Peak Forward Surge Current, 8.3mS single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}					30			A
Maximum Instantaneous Forward Voltage @1.0A	V _F				1.1				V
Maximum DC Reverse Current at Rated DC Blocking voltage per element	I _R	T _A =25 °C			5.0				μA
					50				
Maximum Full Load Reverse Current,full cycle average 0.375"(9.5mm)lead length at T _L =75 °C	I _{R(AV)}				30				μA
Typical Junction Capacitance (Note 1)	C _J				15				pF
Typical Thermal Resistance (Note 2)	R _{θJA}				60				°C/W
Operating Temperature Range	T _J				-55 ~ +150				°C
Storage Temperature Range	T _{STG}				-55 ~ +150				°C

NOTES:

1. Measured at 1.0MHz and Applied Reverse Voltage of 4.0V DC.
2. Thermal Resistance from junction to terminal 6.0mm²copper pads to each terminal.

REV:A

General Purpose Silicon Rectifiers

Comchip
SMD Diode Specialist

Rating and Characteristic Curves (1N4001-G Thru. 1N4007-G)

Fig.1 Typical Forward Current Derating Curve

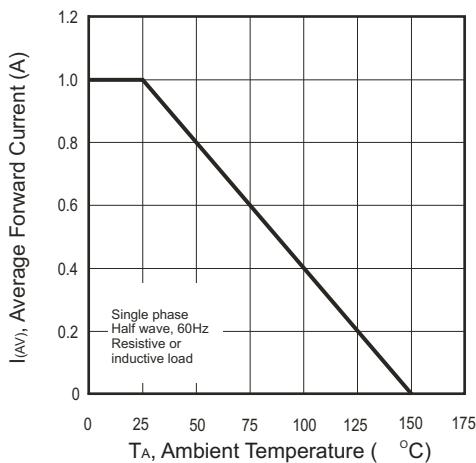


Fig.2 Maximum. Non-Repetitive Peak Forward Surge Current

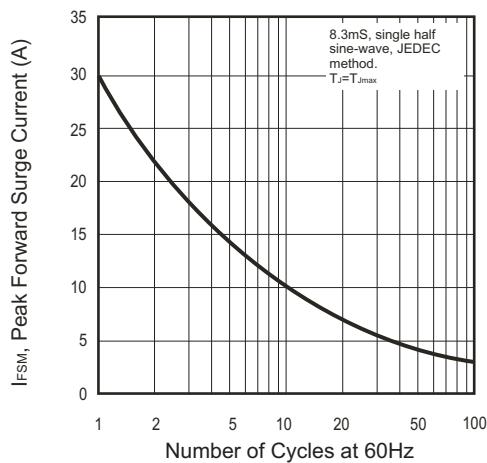


Fig.3 Typical Instantaneous Forward Characteristics

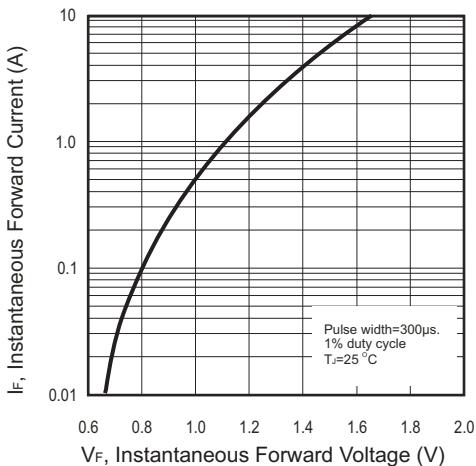


Fig.4 Typical Reverse Characteristics

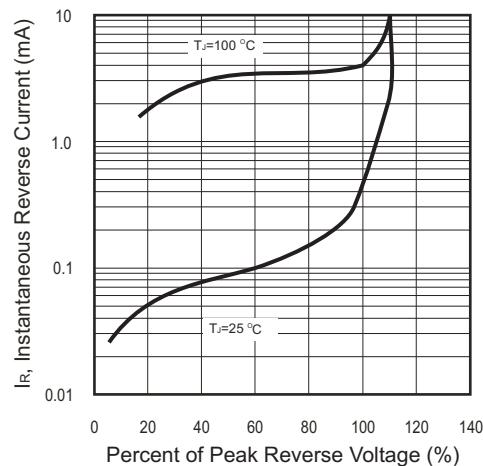


Fig.5 Typical Junction Capacitance

